



***Enhanced Low Dose Rate Sensitivity (ELDRS) Radiation Testing of the
RH3080MK Adjustable Low Dropout Regulator for Linear Technology***

Customer: Linear Technology, PO# X59515L

RAD Job Number: 11-313

Part Type Tested: RH3080MK Adjustable Low Dropout Regulator, Linear Technology RH3080MK SPEC NO. 05-08-5246 REV. 0.

Traceability Information: Fab Lot#: H0946850.1 Wfr#: 4, Assembly Lot#: 595474.1. See photograph of unit under test in Appendix A.

Quantity of Units: 12 units received, 5 units for biased irradiation, 5 units for unbiased irradiation and 2 units for control. Serial numbers 92 to 96 were biased during irradiation, serial numbers 97 to 100, and 117 were unbiased during irradiation and serial numbers 118 and 119 were used as control. See Appendix B for the radiation bias connection table.

Radiation and Electrical Test Increments: 10mrads(Si)/s ionizing radiation with electrical test increments: pre-irradiation, 5krads(Si), 10krads(Si), 20krads(Si), 30krads(Si) and 50krads(Si).

Pre-Irradiation Burn-In: Burn-In performed by Linear Technology prior to receipt by Aeroflex RAD

Overtest and Post-Irradiation Anneal: No overtest. 24-hour room temperature anneal followed by a 168-hour 100°C anneal. Both anneals shall be performed in the same electrical bias condition as the irradiations. Electrical measurements shall be made following each anneal increment.

Radiation Test Standard: MIL-STD-750E TM1019 and/or MIL-STD-883H TM1019 Condition D and Linear Technology RH3080MK SPEC NO. 05-08-5246 REV. 0.

Test Hardware and Software: LTS2020 Automated Tester, Entity ID TS03, Calibration Date: 04-28-11, Calibration Due 04-28-12. LTS2100 Family Board, Entity ID FB01. LTS0606 Test Fixture, Entity ID TF05. RH3080 DUT Board. Test Program: RH3080.SRC

Facility and Radiation Source: Aeroflex RAD's Longmire Laboratories, Colorado Springs, CO. Gamma rays provided by Co60 (GB-150) low dose rate source. Dosimetry performed by Air Ionization Chamber (AIC) traceable to NIST. Aeroflex RAD's dosimetry has been audited by DSCC and Aeroflex RAD has been awarded Laboratory Suitability for MIL-STD-750 and MIL-STD-883 TM 1019.

Irradiation and Test Temperature: Room temperature controlled to 24°C±6°C per MIL-STD-883 and MIL-STD-750.

Low Dose Rate Test Result: PASSED the enhanced low dose rate sensitivity test to the maximum tested dose level of 50krads(Si) with one exception, ISET Line Regulation was out of specification. Note that the variation in ISET Line Regulation of the irradiated units is due to the instruments measurement resolution/precision. Further the units do not exhibit ELDRS as defined in MIL-STD-883H, TM 1019.8.



1.0. Overview and Background

It is well known that total dose ionizing radiation can cause parametric degradation and ultimately functional failure in electronic devices. The damage occurs via electron-hole pair production, transport and trapping in the dielectric regions. In advanced CMOS technology nodes (0.6 μ m and smaller) the bulk of the damage is manifested in the thicker isolation regions, such as shallow trench or local oxidation of silicon (LOCOS) oxides (also known as "birds-beak" oxides). However, many linear and mixed signal devices that utilize bipolar minority carrier elements exhibit an enhanced low dose rate sensitivity (ELDRS). At this time there is no known or accepted *a priori* method for predicting susceptibility to ELDRS or simulating the low dose rate sensitivity with a "conventional" room temperature 50-300rad(Si)/s irradiation (Condition A in MIL-STD-883 TM 1019.8). Over the past 10 years a number of accelerating techniques have been examined, including an elevated temperature anneal, such as that used for MOS devices (see ASTM-F-1892 for more technical details) and irradiating at various temperatures. However, none of these techniques have proven useful across the wide variety of linear and/or mixed signal devices used in spaceborne applications.

The latest requirement incorporated in MIL-STD-883 TM 1019 requires that devices that could potentially exhibit ELDRS "shall be tested either at the intended application dose rate, at a prescribed low dose rate to an overtest radiation level, or with an accelerated test such as an elevated temperature irradiation test that includes a parameter delta design margin". While the recently released MIL-STD-883 TM 1019 allows for accelerated testing, the requirements for this are to essentially perform a low dose rate ELDRS test to verify the suitability of the acceleration method on the component of interest before the acceleration technique can be instituted. Based on the limitations of accelerated testing and to meet the requirements of MIL-STD-883 TM1019.8 Condition D, we have performed a low dose rate test at 10mrad(Si)/s.

2.0. Radiation Test Apparatus

The low dose rate testing described in this final report was performed using the facilities at Aeroflex RAD's Longmire Laboratories in Colorado Springs, CO. The low dose rate source is a GB-150 irradiator modified to provide a panoramic exposure. The Co-60 rods are held in the base of the irradiator heavily shielded by lead. During the irradiation exposures the rod is raised by an electronic timer/controller and the exposure is performed in air. The dose rate for this irradiator in this configuration ranges from approximately 1mrad(Si)/s to a maximum of approximately 50rad(Si)/s, determined by the distance from the source. For low dose rate testing described in this report, the devices are placed approximately 2-meters from the Co-60 rods. The irradiator calibration is maintained by Aeroflex RAD's Longmire Laboratories using air ionization chamber (AIC) dosimetry traceable to the National Institute of Standards and Technology (NIST). Figure 2.1 shows a photograph of the GB-150 Co-60 irradiator at Aeroflex RAD's Longmire Laboratory facility.



Figure 2.1. Aeroflex RAD's Co-60 irradiator. The dose rate is obtained by positioning the device-under-test at a fixed distance from the gamma cell. The dose rate for this irradiator varies from approximately 50rad(Si)/s close to the rods down to <1mrad(Si)/s at a distance of approximately 4-meters.



3.0. Radiation Test Conditions

The RH3080MK Adjustable Low Dropout Regulator described in this final report were irradiated using a single-sided supply potential of 3V and with all pins tied to ground, that is biased and unbiased. See Appendix B for details on the biasing conditions during radiation exposure. In our opinion, this bias circuit satisfies the requirements of MIL-STD-883H TM1019.8 Section 3.9.3 Bias and Loading Conditions which states "The bias applied to the test devices shall be selected to produce the greatest radiation induced damage or the worst-case damage for the intended application, if known. While maximum voltage is often worst case some bipolar linear device parameters (e.g. input bias current or maximum output load current) exhibit more degradation with 0 V bias."

The devices were irradiated to a maximum total ionizing dose level of 50krad(Si) with incremental readings at 5krad(Si), 10krad(Si), 20krad(Si) and 30krad(Si). Electrical testing occurred within one hour following the end of each irradiation segment. For intermediate irradiations, the units were tested and returned to total dose exposure within two hours from the end of the previous radiation increment. The radiation exposure bias board was positioned in the Co-60 cell to provide the targeted dose rate and was located inside a lead-aluminum enclosure. The lead-aluminum enclosure is required under MIL-STD-883H TM1019.8 Section 3.4 that reads as follows: "Lead/Aluminum (Pb/Al) container. Test specimens shall be enclosed in a Pb/Al container to minimize dose enhancement effects caused by low-energy, scattered radiation. A minimum of 1.5 mm Pb, surrounding an inner shield of at least 0.7 mm Al, is required. This Pb/Al container produces an approximate charged particle equilibrium for Si and for TLDs such as CaF₂. The radiation field intensity shall be measured inside the Pb/Al container (1) initially, (2) when the source is changed, or (3) when the orientation or configuration of the source, container, or test-fixture is changed. This measurement shall be performed by placing a dosimeter (e.g., a TLD) in the device-irradiation container at the approximate test-device position. If it can be demonstrated that low energy scattered radiation is small enough that it will not cause dosimetry errors due to dose enhancement, the Pb/Al container may be omitted".

The final dose rate within the lead-aluminum box was determined based on air ionization chamber (AIC) dosimetry measurements just prior to the beginning of the total dose irradiations. The final dose rate for this work was 10mrad(Si)/s with a precision of $\pm 5\%$.



4.0. Tested Parameters

During the enhanced low dose rate sensitivity testing the following electrical parameters were measured pre- and post-irradiation:

1. SET Pin Current (A) @ $V_{in}=1V$ $V_c=2V$ $I_L=1mA$
2. Output Offset Voltage (V) @ $V_{in}=1V$ $V_c=2V$ $I_L=1mA$
3. ISET Line Regulation (nA/V) @ $V_c=2$ to $26V$ $I_L=1mA$
4. VOS Line Regulation (mV/V) @ $V_c=2$ to $26V$ $I_L=1mA$
5. ISET Load Regulation (A) @ $I_L=1mA$ to $100mA$
6. VOS Load Regulation (V) @ $I_L=1mA$ to $100mA$
7. VCONTROL Pin Current (A) @ $V_{in}=1V$ $V_c=2V$ $I_L=100mA$
8. Minimum Load Current (A) @ $V_{in}=V_c=10V$ $V_o=0.1V$
9. Minimum Load Current (A) @ $V_{in}=V_c=26V$ $V_o=0.1V$
10. VCONTROL Dropout Voltage (V) @ $V_{in}=1V$ $I_L=100mA$
11. VIN Dropout Voltage (V) @ $V_c=2V$ $I_L=100mA$

Appendix C details the measured parameters, test conditions, pre-irradiation specification and measurement resolution for each of the measurements.

The parametric data was obtained as "read and record" and all the raw data plus an attributes summary are contained in this report as well as in a separate Excel file. The attributes data contains the average, standard deviation and the average with the KTL values applied. The KTL value used in this work is 2.742 per MIL-HDBK-814 using one sided tolerance limits of 90/90 and a 5-piece sample size. The 90/90 KTL values were selected to match the statistical levels specified in the MIL-PRF-38535 sampling plan for the qualification of a radiation hardness assured (RHA) component. Note that the following criteria must be met for a device to pass the low dose rate test: following the radiation exposure each of the 5 pieces irradiated under electrical bias shall pass the specification value. The units irradiated without electrical bias and the KTL statistics are included in this report for reference only. If any of the 5 pieces irradiated under electrical bias exceed the device post radiation data sheet specification limits, then the lot could be logged as a failure.

Further, MIL-STD-883H, TM 1019.8 Section 3.13.1.1 Characterization test to determine if a part exhibits ELDRS' states the following: Select a minimum random sample of 21 devices from a population representative of recent production runs. Smaller sample sizes may be used if agreed upon between the parties to the test. All of the selected devices shall have undergone appropriate elevated temperature reliability screens, e.g. burn-in and high temperature storage life. Divide the samples into four groups of 5 each and use the remaining part for a control. Perform pre-irradiation electrical characterization on all parts assuring that they meet the Group A electrical tests. Irradiate 5 samples under a 0 volt bias and another 5 under the irradiation bias given in the acquisition specification at 50-300 rad(Si)/s and room temperature. Irradiate 5 samples under a 0 volt bias and another 5 under irradiation bias given in the acquisition specification at < 10mrad(Si)/s and room temperature. Irradiate



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all samples to the same dose levels, including 0.5 and 1.0 times the anticipated specification dose, and repeat the electrical characterization on each part at each dose level. Post irradiation electrical measurements shall be performed per paragraph 3.10 where the low dose rate test is considered Condition D. Calculate the radiation induced change in each electrical parameter (Δ para) for each sample at each radiation level. Calculate the ratio of the median Δ para at low dose rate to the median Δ para at high dose rate for each irradiation bias group at each total dose level. If this ratio exceeds 1.5 for any of the most sensitive parameters then the part is considered to be ELDRS susceptible. This test does not apply to parameters which exhibit changes that are within experimental error or whose values are below the pre-irradiation electrical specification limits at low dose rate at the specification dose.

Therefore, the data in this report can be analyzed along with the high dose rate report titled "Total Ionizing Dose (TID) Radiation Testing of the RH3080MK Adjustable Low Dropout Regulator for Linear Technology" to demonstrate that these parts do not exhibit ELDRS as defined in the current test method.



5.0. ELDRS Test Results

Based on this criterion the RH3080MK Adjustable Low Dropout Regulator (from the lot traceability information provided on the first page of this test report) PASSED the enhanced low dose rate sensitivity test to the maximum tested dose level of 50krad(Si) with one exception, ISET Line Regulation was out of specification. Note that the variation in ISET Line Regulation of the irradiated units is due to the instruments measurement resolution/precision (see Table C2).

Figures 5.1 through 5.12 show plots of all the measured parameters versus total ionizing dose while Tables 5.1 - 5.12 show the corresponding raw data for each of these parameters. In the data plots the solid diamonds are the average of the measured data points for the sample irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the units irradiated with all pins tied to ground. The black lines (solid or dashed) are the average of the data points after application of the KTL statistics on the sample irradiated in the biased condition while the shaded lines (solid or dashed) are the average of the data points after application of the KTL statistics on the sample irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.

In addition to the radiation test results, the data plots and tables described above contain anneal data. The anneals are performed to better understand the underlying physical mechanisms responsible for radiation-induced parametric shifts and are not part of the criteria used to establish whether or not the lot passes or fails the low dose rate test. In all cases the parts either improved or exhibited no change during the anneal.

The control units, as expected, show no significant changes to any of the parameters. Therefore we can conclude that the electrical testing remained in control throughout the duration of the tests and the observed degradation was due to the radiation exposure. Appendix D lists the figures used in this section to facilitate the location of a particular parameter.

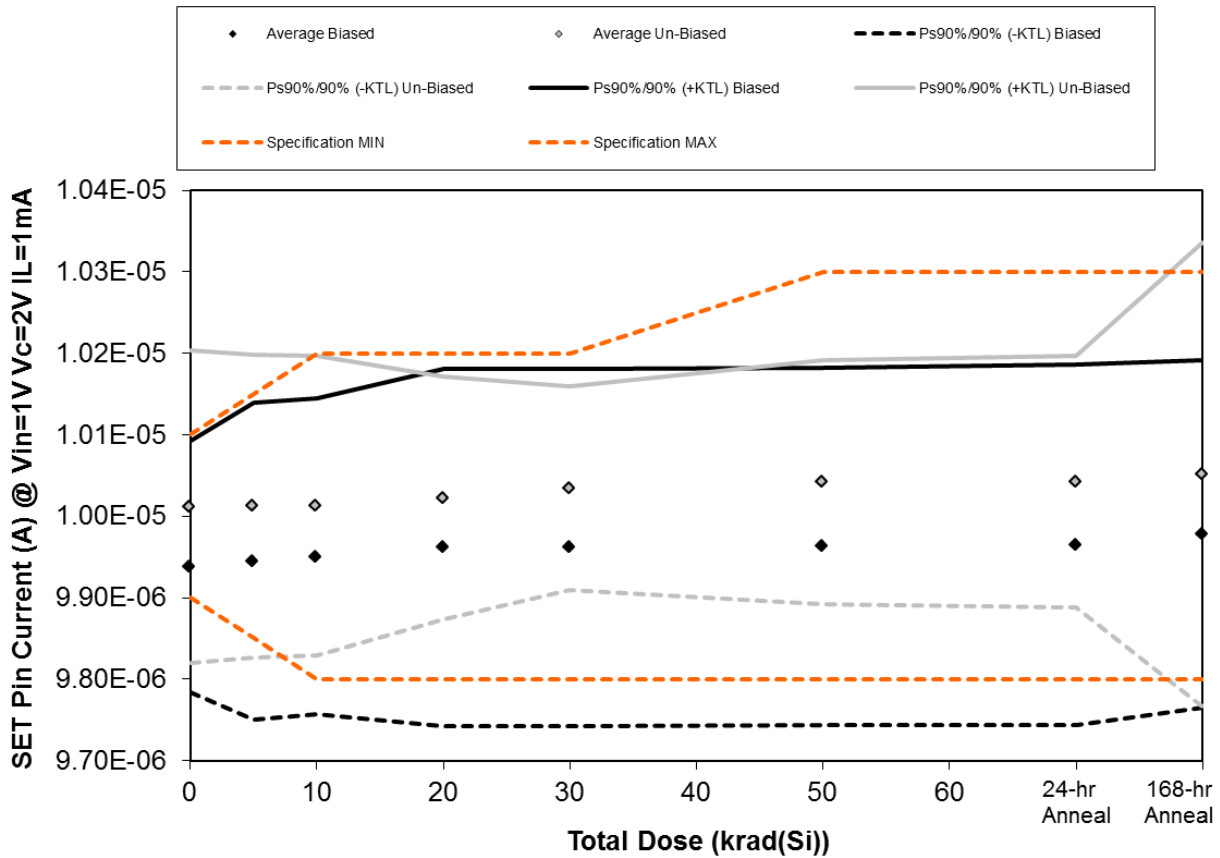


Figure 5.1. Plot of SET Pin Current (A) @ $V_{in}=1V$ $V_c=2V$ $I_L=1mA$ versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.1. Raw data for SET Pin Current (A) @ Vin=1V Vc=2V IL=1mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

SET Pin Current (A) @ Vin=1V Vc=2V IL=1mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device	0	5	10	20	30	50			
92	9.912E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.916E-06
93	1.004E-05	1.007E-05	1.008E-05	1.010E-05	1.010E-05	1.010E-05	1.010E-05	1.010E-05	1.010E-05
94	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06
95	9.913E-06	9.913E-06	9.939E-06	9.974E-06	9.974E-06	9.979E-06	9.987E-06	9.987E-06	1.001E-05
96	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.913E-06	9.951E-06
97	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05
98	1.010E-05	1.010E-05	1.010E-05	1.010E-05	1.010E-05	1.013E-05	1.013E-05	1.013E-05	1.022E-05
99	9.975E-06	9.974E-06	9.975E-06	9.998E-06	1.003E-05	1.004E-05	1.004E-05	1.004E-05	1.003E-05
100	9.913E-06	9.919E-06	9.921E-06	9.949E-06	9.968E-06	9.974E-06	9.975E-06	9.975E-06	9.932E-06
117	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05	1.004E-05
118	1.002E-05	1.003E-05	1.003E-05	1.003E-05	1.002E-05	1.002E-05	1.003E-05	1.003E-05	1.003E-05
119	1.003E-05	1.003E-05	1.003E-05	1.003E-05	1.003E-05	1.003E-05	1.003E-05	1.003E-05	1.003E-05
Biased Statistics									
Average Biased	9.94E-06	9.94E-06	9.95E-06	9.96E-06	9.96E-06	9.96E-06	9.96E-06	9.96E-06	9.98E-06
Std Dev Biased	5.65E-08	7.11E-08	7.09E-08	8.00E-08	8.00E-08	8.02E-08	8.07E-08	8.07E-08	7.79E-08
Ps90%/90% (+KTL) Biased	1.01E-05	1.01E-05	1.01E-05	1.02E-05	1.02E-05	1.02E-05	1.02E-05	1.02E-05	1.02E-05
Ps90%/90% (-KTL) Biased	9.78E-06	9.75E-06	9.76E-06	9.74E-06	9.74E-06	9.74E-06	9.74E-06	9.74E-06	9.76E-06
Un-Biased Statistics									
Average Un-Biased	1.00E-05	1.00E-05	1.00E-05	1.00E-05	1.00E-05	1.00E-05	1.00E-05	1.00E-05	1.01E-05
Std Dev Un-Biased	6.99E-08	6.80E-08	6.71E-08	5.45E-08	4.56E-08	5.47E-08	5.63E-08	5.63E-08	1.04E-07
Ps90%/90% (+KTL) Un-Biased	1.02E-05	1.02E-05	1.02E-05	1.02E-05	1.02E-05	1.02E-05	1.02E-05	1.02E-05	1.03E-05
Ps90%/90% (-KTL) Un-Biased	9.82E-06	9.83E-06	9.83E-06	9.87E-06	9.91E-06	9.89E-06	9.89E-06	9.89E-06	9.77E-06
Specification MIN	9.90E-06		9.80E-06	9.80E-06		9.80E-06	9.80E-06	9.80E-06	9.80E-06
Status	PASS		PASS	PASS		PASS	PASS	PASS	PASS
Specification MAX	1.01E-05		1.02E-05	1.02E-05		1.03E-05	1.03E-05	1.03E-05	1.03E-05
Status	PASS		PASS	PASS		PASS	PASS	PASS	PASS

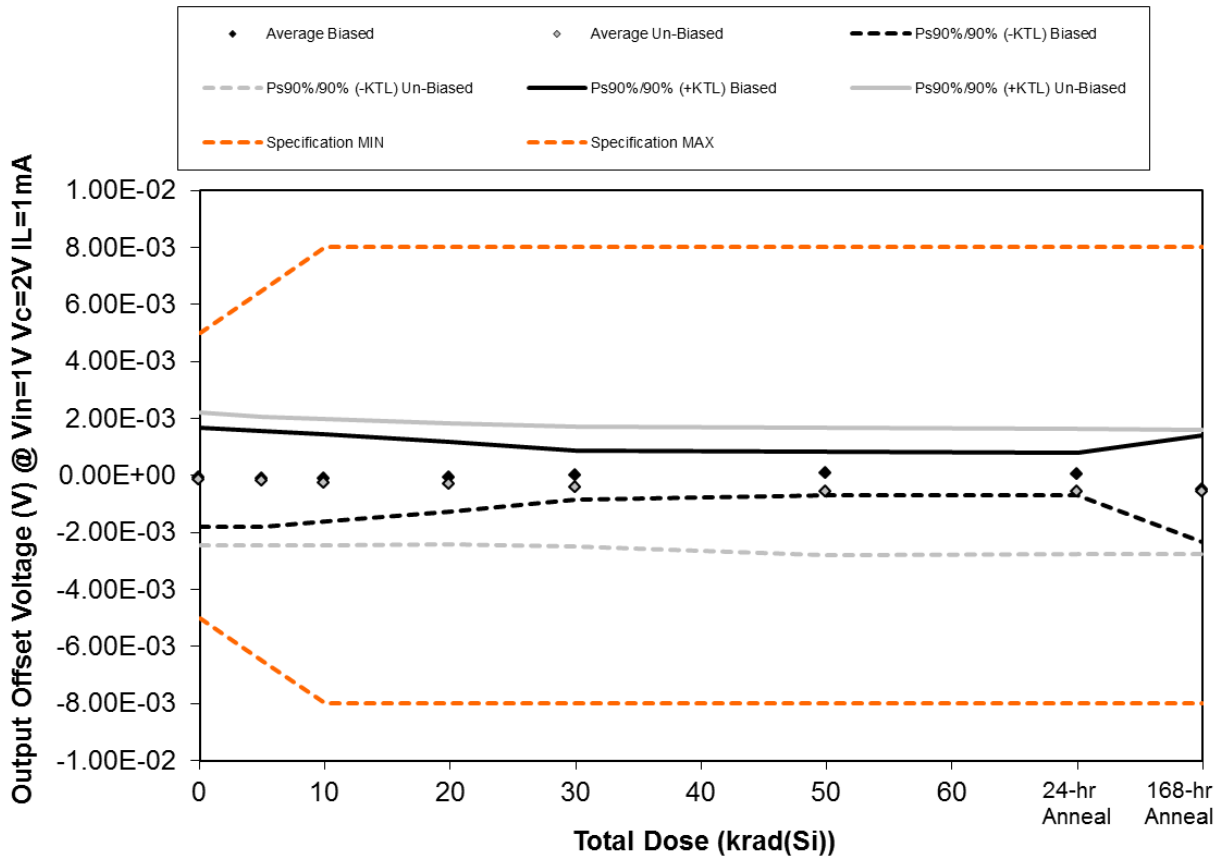


Figure 5.2. Plot of Output Offset Voltage (V) @ $V_{in}=1V$ $V_c=2V$ $I_L=1mA$ versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.2. Raw data for Output Offset Voltage (V) @ Vin=1V Vc=2V IL=1mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

Output Offset Voltage (V) @ Vin=1V Vc=2V IL=1mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device		0	5	10	20	30	50		
92	-6.66E-04	-6.81E-04	-5.71E-04	-4.33E-04	-2.47E-04	6.00E-05	3.20E-05	-1.20E-03	
93	-7.78E-04	-8.05E-04	-7.25E-04	-5.21E-04	-2.39E-04	1.81E-04	1.53E-04	-1.19E-03	
94	3.60E-05	-5.00E-06	-2.50E-05	-2.00E-05	-3.90E-05	-6.20E-05	-7.20E-05	-7.80E-05	
95	3.91E-04	2.88E-04	2.52E-04	1.78E-04	4.30E-05	-2.60E-04	-2.57E-04	-1.46E-04	
96	6.68E-04	6.28E-04	6.04E-04	5.65E-04	5.16E-04	4.83E-04	4.73E-04	2.64E-04	
97	-1.16E-03	-1.21E-03	-1.24E-03	-1.21E-03	-1.23E-03	-1.26E-03	-1.25E-03	-1.23E-03	
98	5.51E-04	3.58E-04	2.43E-04	-2.60E-05	-3.45E-04	-9.11E-04	-8.89E-04	-2.55E-04	
99	-9.40E-04	-9.47E-04	-9.89E-04	-1.02E-03	-1.10E-03	-1.24E-03	-1.23E-03	-1.58E-03	
100	3.09E-04	2.91E-04	2.72E-04	2.43E-04	2.23E-04	1.65E-04	1.64E-04	-4.90E-05	
117	5.94E-04	5.55E-04	5.20E-04	5.12E-04	4.92E-04	4.52E-04	4.50E-04	2.65E-04	
118	-6.04E-04	-5.89E-04	-5.89E-04	-5.99E-04	-5.90E-04	-5.88E-04	-5.92E-04	-5.76E-04	
119	2.16E-04	2.75E-04	2.80E-04	2.61E-04	3.10E-04	2.96E-04	2.92E-04	2.09E-04	
Biased Statistics									
Average Biased	-6.98E-05	-1.15E-04	-9.30E-05	-4.62E-05	6.80E-06	8.04E-05	6.58E-05	-4.70E-04	
Std Dev Biased	6.37E-04	6.17E-04	5.56E-04	4.47E-04	3.11E-04	2.78E-04	2.73E-04	6.80E-04	
Ps90%/90% (+KTL) Biased	1.68E-03	1.58E-03	1.43E-03	1.18E-03	8.60E-04	8.42E-04	8.14E-04	1.39E-03	
Ps90%/90% (-KTL) Biased	-1.82E-03	-1.81E-03	-1.62E-03	-1.27E-03	-8.47E-04	-6.81E-04	-6.82E-04	-2.33E-03	
Un-Biased Statistics									
Average Un-Biased	-1.28E-04	-1.90E-04	-2.39E-04	-3.00E-04	-3.91E-04	-5.58E-04	-5.52E-04	-5.70E-04	
Std Dev Un-Biased	8.50E-04	8.21E-04	8.12E-04	7.71E-04	7.67E-04	8.09E-04	8.04E-04	7.95E-04	
Ps90%/90% (+KTL) Un-Biased	2.20E-03	2.06E-03	1.99E-03	1.81E-03	1.71E-03	1.66E-03	1.65E-03	1.61E-03	
Ps90%/90% (-KTL) Un-Biased	-2.46E-03	-2.44E-03	-2.46E-03	-2.41E-03	-2.50E-03	-2.78E-03	-2.76E-03	-2.75E-03	
Specification MIN	-5.00E-03		-8.00E-03	-8.00E-03		-8.00E-03	-8.00E-03	-8.00E-03	
Status	PASS		PASS	PASS		PASS	PASS	PASS	
Specification MAX	5.00E-03		8.00E-03	8.00E-03		8.00E-03	8.00E-03	8.00E-03	
Status	PASS		PASS	PASS		PASS	PASS	PASS	

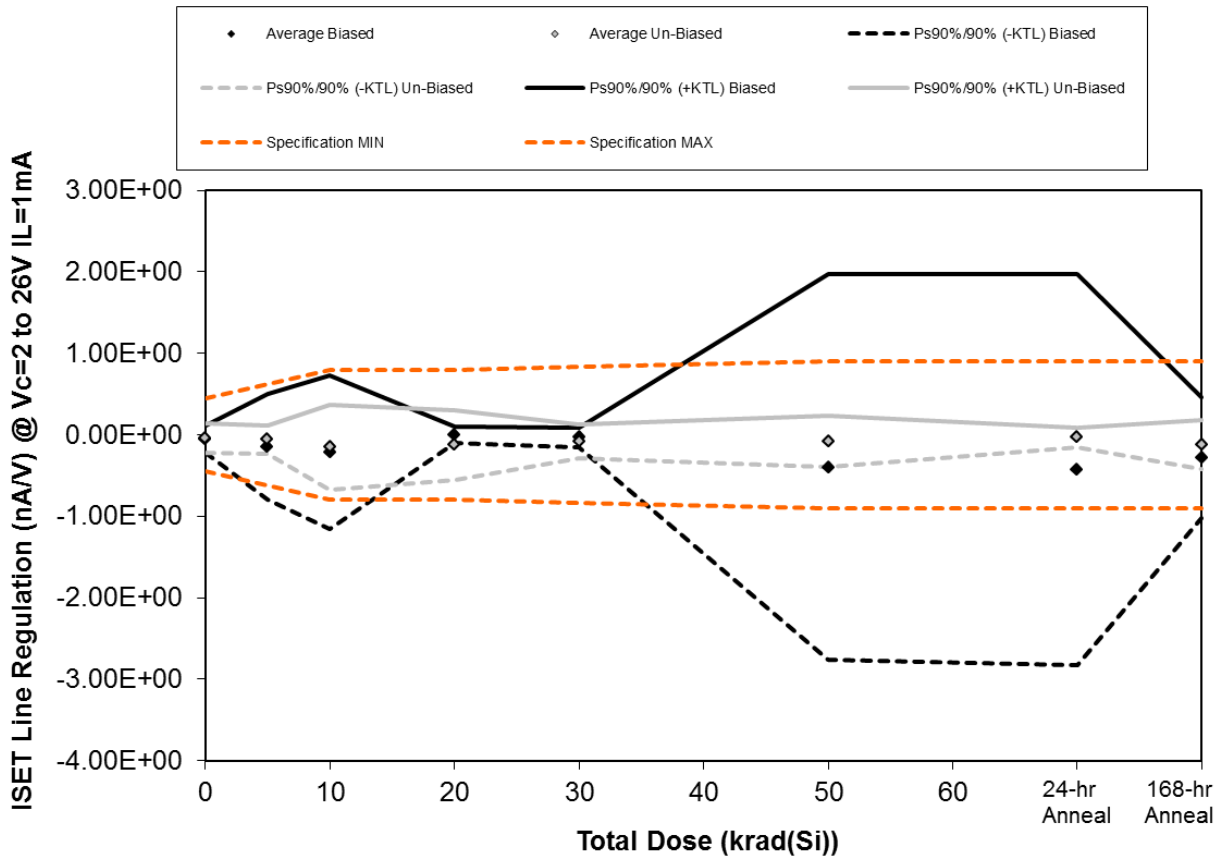


Figure 5.3. Plot of ISET Line Regulation (nA/V) @ Vc=2 to 26V IL=1mA versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.3. Raw data for ISET Line Regulation (nA/V) @ Vc=2 to 26V IL=1mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

ISET Line Regulation (nA/V) @ Vc=2 to 26V IL=1mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device		0	5	10	20	30	50		
92	-5.00E-02	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-2.50E-01
93	-1.50E-01	-1.50E-01	-2.00E-01	5.00E-02	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-5.00E-02
94	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-5.00E-02	0.00E+00
95	-5.00E-02	-5.60E-01	-8.10E-01	0.00E+00	-5.00E-02	-1.94E+00	-1.99E+00	-5.10E-01	
96	0.00E+00	-5.00E-02	-5.00E-02	-5.00E-02	-1.00E-01	-5.00E-02	-1.00E-01	-6.10E-01	
97	0.00E+00	-5.00E-02	0.00E+00	0.00E+00	-5.00E-02	-1.50E-01	-1.00E-01	-5.00E-02	
98	0.00E+00	0.00E+00	-5.00E-02	-5.00E-02	-2.00E-01	-2.50E-01	0.00E+00	-5.00E-02	
99	-5.00E-02	-1.50E-01	-3.10E-01	-3.60E-01	-5.00E-02	0.00E+00	0.00E+00	-1.00E-01	
100	-1.50E-01	-1.00E-01	-4.10E-01	-2.00E-01	-1.00E-01	0.00E+00	0.00E+00	-3.10E-01	
117	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-5.00E-02	-1.00E-01	
118	-2.00E-01	1.00E-01	1.50E-01	2.00E-01	-2.50E-01	5.00E-02	-3.10E-01	0.00E+00	
119	1.50E-01	-5.00E-02	5.00E-02	0.00E+00	-1.00E-01	5.00E-02	1.00E-01	-1.00E-01	
Biased Statistics									
Average Biased	-5.00E-02	-1.52E-01	-2.12E-01	0.00E+00	-3.00E-02	-3.98E-01	-4.28E-01	-2.84E-01	
Std Dev Biased	6.12E-02	2.36E-01	3.44E-01	3.54E-02	4.47E-02	8.62E-01	8.74E-01	2.71E-01	
Ps90%/90% (+KTL) Biased	1.18E-01	4.96E-01	7.32E-01	9.69E-02	9.26E-02	1.97E+00	1.97E+00	4.59E-01	
Ps90%/90% (-KTL) Biased	-2.18E-01	-8.00E-01	-1.16E+00	-9.69E-02	-1.53E-01	-2.76E+00	-2.82E+00	-1.03E+00	
Un-Biased Statistics									
Average Un-Biased	-4.00E-02	-6.00E-02	-1.54E-01	-1.22E-01	-8.00E-02	-8.00E-02	-3.00E-02	-1.22E-01	
Std Dev Un-Biased	6.52E-02	6.52E-02	1.92E-01	1.56E-01	7.58E-02	1.15E-01	4.47E-02	1.08E-01	
Ps90%/90% (+KTL) Un-Biased	1.39E-01	1.19E-01	3.74E-01	3.06E-01	1.28E-01	2.36E-01	9.26E-02	1.74E-01	
Ps90%/90% (-KTL) Un-Biased	-2.19E-01	-2.39E-01	-6.82E-01	-5.50E-01	-2.88E-01	-3.96E-01	-1.53E-01	-4.18E-01	
Specification MIN	-4.50E-01		-8.00E-01	-8.00E-01		-9.00E-01	-9.00E-01	-9.00E-01	
Status	PASS		FAIL	PASS		FAIL	FAIL	PASS	
Specification MAX	4.50E-01		8.00E-01	8.00E-01		9.00E-01	9.00E-01	9.00E-01	
Status	PASS		PASS	PASS		PASS	PASS	PASS	

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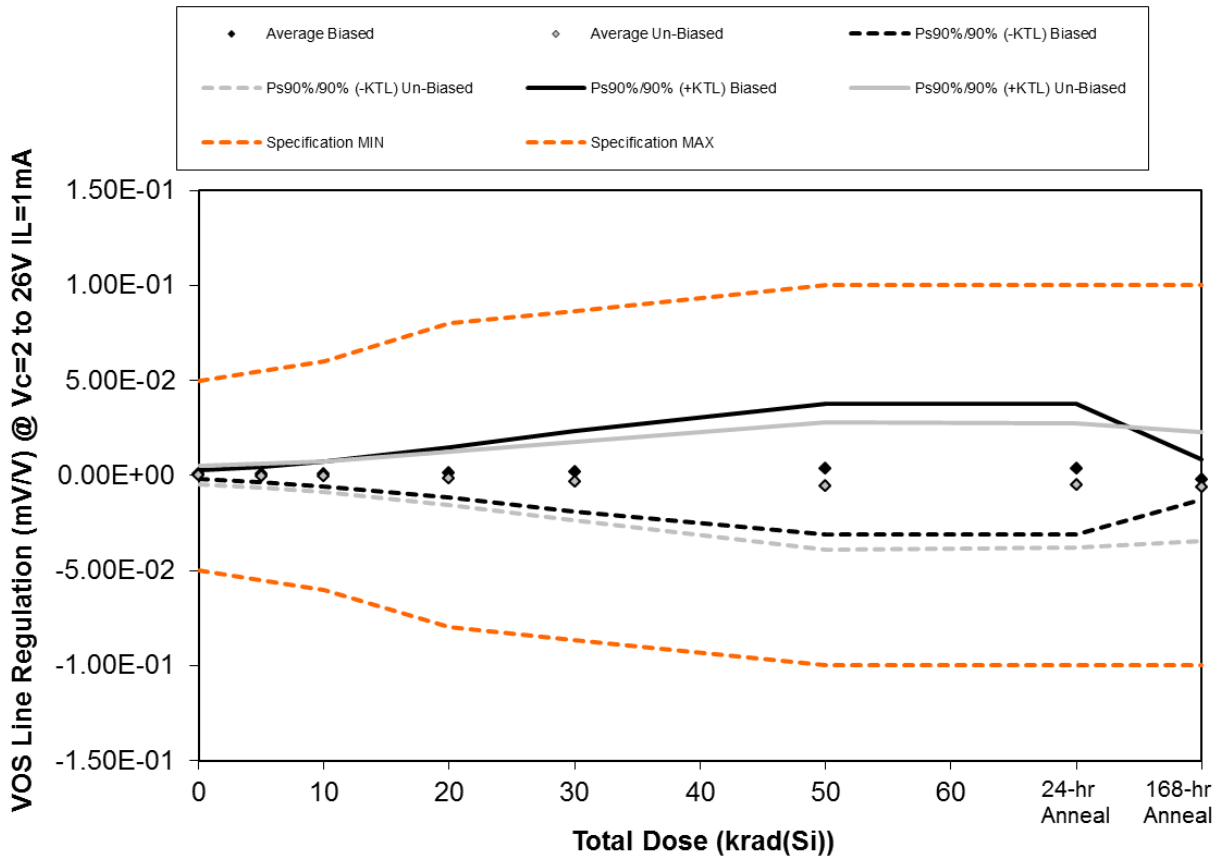


Figure 5.4. Plot of VOS Line Regulation (mV/V) @ $V_c=2$ to 26V $I_L=1$ mA versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.4. Raw data for VOS Line Regulation (mV/V) @ Vc=2 to 26V IL=1mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

VOS Line Regulation (mV/V) @ Vc=2 to 26V IL=1mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device		0	5	10	20	30	50		
92	2.00E-03	3.00E-03	4.00E-03	7.00E-03	1.00E-02	1.50E-02	1.50E-02	2.00E-03	
93	1.00E-03	1.00E-03	2.00E-03	6.00E-03	1.10E-02	1.80E-02	1.80E-02	0.00E+00	
94	0.00E+00	0.00E+00	-1.00E-03	-1.00E-03	-2.00E-03	-2.00E-03	-2.00E-03	-1.00E-03	
95	0.00E+00	-1.00E-03	-2.00E-03	-4.00E-03	-6.00E-03	-1.10E-02	-1.10E-02	-8.00E-03	
96	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-2.00E-03	-3.00E-03	-3.00E-03	-3.00E-03	
97	2.00E-03	2.00E-03	2.00E-03	2.00E-03	2.00E-03	1.00E-03	1.00E-03	3.00E-03	
98	-2.00E-03	-3.00E-03	-5.00E-03	-1.00E-02	-1.60E-02	-2.70E-02	-2.60E-02	-1.90E-02	
99	2.00E-03	2.00E-03	2.00E-03	3.00E-03	2.00E-03	3.00E-03	3.00E-03	6.00E-03	
100	-1.00E-03	-2.00E-03	-2.00E-03	-2.00E-03	-3.00E-03	-3.00E-03	-3.00E-03	-1.20E-02	
117	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-1.00E-03	-1.00E-03	-8.00E-03	
118	1.00E-03	1.00E-03	1.00E-03	1.00E-03	2.00E-03	2.00E-03	2.00E-03	2.00E-03	
119	2.00E-03	2.00E-03	2.00E-03	2.00E-03	2.00E-03	2.00E-03	2.00E-03	2.00E-03	
Biased Statistics									
Average Biased	6.00E-04	6.00E-04	6.00E-04	1.60E-03	2.20E-03	3.40E-03	3.40E-03	-2.00E-03	
Std Dev Biased	8.94E-04	1.52E-03	2.41E-03	4.72E-03	7.76E-03	1.25E-02	1.25E-02	3.81E-03	
Ps90%/90% (+KTL) Biased	3.05E-03	4.76E-03	7.20E-03	1.45E-02	2.35E-02	3.77E-02	3.77E-02	8.44E-03	
Ps90%/90% (-KTL) Biased	-1.85E-03	-3.56E-03	-6.00E-03	-1.13E-02	-1.91E-02	-3.09E-02	-3.09E-02	-1.24E-02	
Un-Biased Statistics									
Average Un-Biased	2.00E-04	-2.00E-04	-6.00E-04	-1.40E-03	-3.00E-03	-5.40E-03	-5.20E-03	-6.00E-03	
Std Dev Un-Biased	1.79E-03	2.28E-03	2.97E-03	5.18E-03	7.55E-03	1.23E-02	1.18E-02	1.04E-02	
Ps90%/90% (+KTL) Un-Biased	5.11E-03	6.05E-03	7.53E-03	1.28E-02	1.77E-02	2.83E-02	2.73E-02	2.26E-02	
Ps90%/90% (-KTL) Un-Biased	-4.71E-03	-6.45E-03	-8.73E-03	-1.56E-02	-2.37E-02	-3.91E-02	-3.77E-02	-3.46E-02	
Specification MIN	-5.00E-02		-6.00E-02	-8.00E-02		-1.00E-01	-1.00E-01	-1.00E-01	
Status	PASS		PASS	PASS		PASS	PASS	PASS	
Specification MAX	5.00E-02		6.00E-02	8.00E-02		1.00E-01	1.00E-01	1.00E-01	
Status	PASS		PASS	PASS		PASS	PASS	PASS	

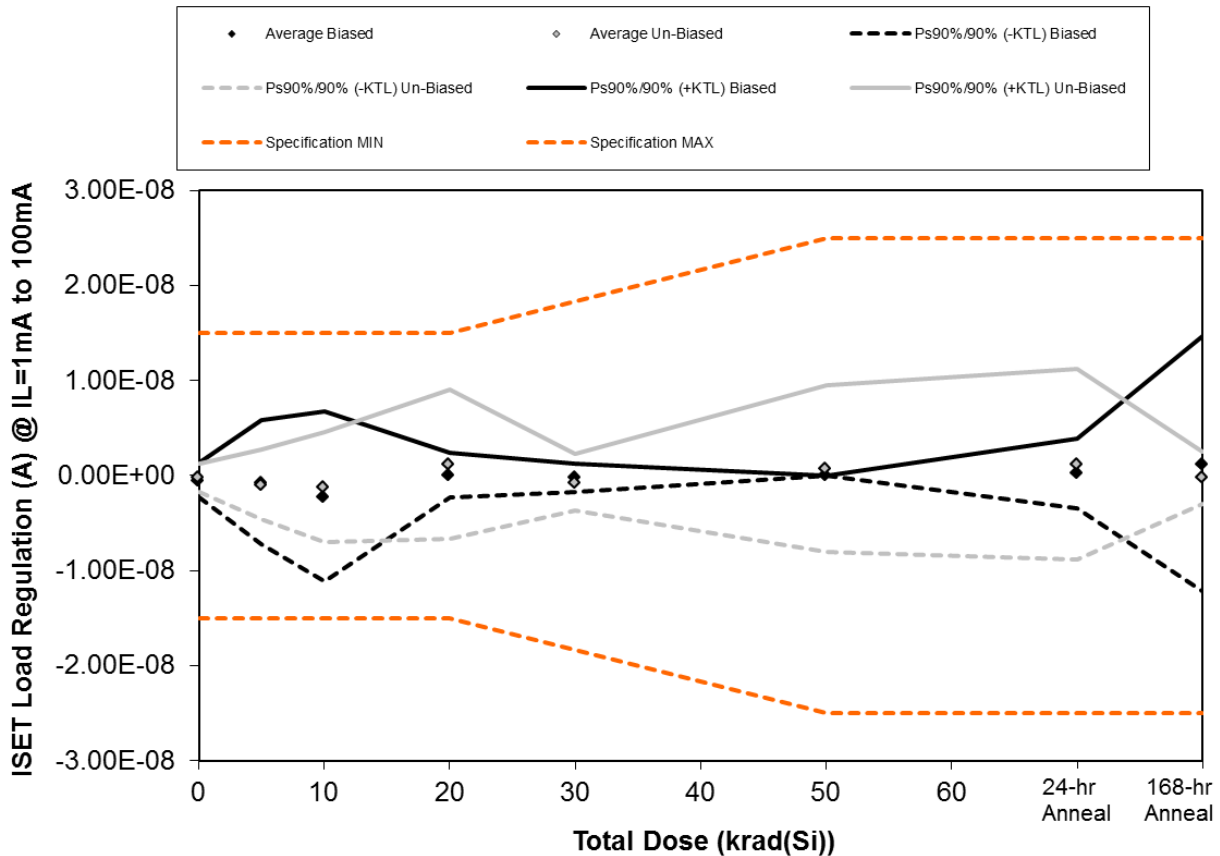


Figure 5.5. Plot of ISET Load Regulation (A) @ IL=1mA to 100mA versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.5. Raw data for ISET Load Regulation (A) @ IL=1mA to 100mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

ISET Load Regulation (A) @ IL=1mA to 100mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device	0	5	10	20	30	50			
92	-1.22E-09	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00
93	0.00E+00	1.22E-09	-3.67E-09	1.22E-09	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-1.22E-09
94	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00
95	-1.22E-09	-4.89E-09	-7.33E-09	0.00E+00	0.00E+00	0.00E+00	0.00E+00	2.44E-09	9.78E-09
96	0.00E+00	0.00E+00	0.00E+00	-1.22E-09	-1.22E-09	0.00E+00	-1.22E-09	-2.44E-09	-2.44E-09
97	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-2.44E-09	-2.44E-09	0.00E+00	0.00E+00
98	0.00E+00	0.00E+00	0.00E+00	-1.22E-09	-2.44E-09	6.11E-09	7.33E-09	0.00E+00	0.00E+00
99	0.00E+00	-2.44E-09	-4.89E-09	6.11E-09	-1.22E-09	0.00E+00	0.00E+00	1.22E-09	1.22E-09
100	-1.22E-09	-2.44E-09	-1.22E-09	1.22E-09	0.00E+00	0.00E+00	1.22E-09	-1.22E-09	-1.22E-09
117	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	-1.22E-09	-1.22E-09
118	-6.11E-09	-1.22E-09	-1.22E-09	1.22E-09	-4.89E-09	0.00E+00	0.00E+00	0.00E+00	0.00E+00
119	-2.44E-09	-1.22E-09	1.22E-09	1.22E-09	1.22E-09	-2.44E-09	2.44E-09	0.00E+00	0.00E+00
Biased Statistics									
Average Biased	-4.88E-10	-7.34E-10	-2.20E-09	0.00E+00	-2.44E-10	0.00E+00	2.44E-10	1.22E-09	1.22E-09
Std Dev Biased	6.68E-10	2.38E-09	3.28E-09	8.63E-10	5.46E-10	0.00E+00	1.34E-09	4.89E-09	4.89E-09
Ps90%/90% (+KTL) Biased	1.34E-09	5.80E-09	6.79E-09	2.37E-09	1.25E-09	0.00E+00	3.91E-09	1.46E-08	1.46E-08
Ps90%/90% (-KTL) Biased	-2.32E-09	-7.27E-09	-1.12E-08	-2.37E-09	-1.74E-09	0.00E+00	-3.42E-09	-1.22E-08	-1.22E-08
Un-Biased Statistics									
Average Un-Biased	-2.44E-10	-9.76E-10	-1.22E-09	1.22E-09	-7.32E-10	7.34E-10	1.22E-09	-2.44E-10	-2.44E-10
Std Dev Un-Biased	5.46E-10	1.34E-09	2.12E-09	2.87E-09	1.09E-09	3.19E-09	3.66E-09	1.02E-09	1.02E-09
Ps90%/90% (+KTL) Un-Biased	1.25E-09	2.69E-09	4.58E-09	9.08E-09	2.26E-09	9.47E-09	1.13E-08	2.55E-09	2.55E-09
Ps90%/90% (-KTL) Un-Biased	-1.74E-09	-4.64E-09	-7.03E-09	-6.63E-09	-3.72E-09	-8.00E-09	-8.83E-09	-3.04E-09	-3.04E-09
Specification MIN	-1.50E-08		-1.50E-08	-1.50E-08		-2.50E-08	-2.50E-08	-2.50E-08	-2.50E-08
Status	PASS		PASS	PASS		PASS	PASS	PASS	PASS
Specification MAX	1.50E-08		1.50E-08	1.50E-08		2.50E-08	2.50E-08	2.50E-08	2.50E-08
Status	PASS		PASS	PASS		PASS	PASS	PASS	PASS

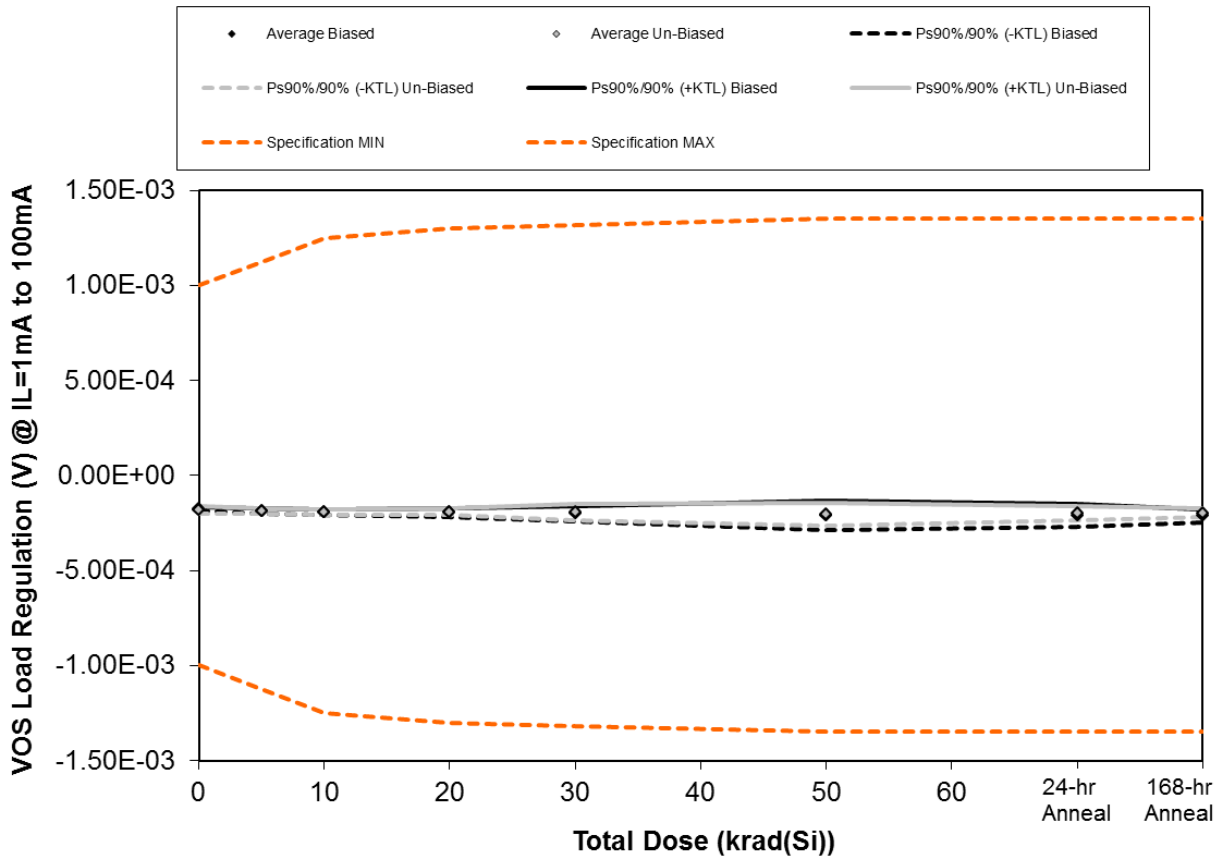


Figure 5.6. Plot of VOS Load Regulation (V) @ IL=1mA to 100mA versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.6. Raw data for VOS Load Regulation (V) @ IL=1mA to 100mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

VOS Load Regulation (V) @ IL=1mA to 100mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device	0	5	10	20	30	50			
92	-1.71E-04	-1.89E-04	-1.88E-04	-1.93E-04	-1.96E-04	-1.95E-04	-2.01E-04	-2.18E-04	
93	-1.73E-04	-1.84E-04	-1.97E-04	-1.96E-04	-1.96E-04	-2.09E-04	-2.13E-04	-2.18E-04	
94	-1.80E-04	-1.86E-04	-1.89E-04	-1.85E-04	-1.88E-04	-1.96E-04	-1.95E-04	-1.92E-04	
95	-1.74E-04	-1.93E-04	-1.97E-04	-2.08E-04	-2.25E-04	-2.62E-04	-2.50E-04	-2.11E-04	
96	-1.79E-04	-1.81E-04	-1.90E-04	-1.95E-04	-1.98E-04	-1.98E-04	-2.02E-04	-2.24E-04	
97	-1.72E-04	-1.77E-04	-1.89E-04	-1.88E-04	-1.79E-04	-1.95E-04	-1.87E-04	-1.84E-04	
98	-1.73E-04	-1.90E-04	-1.93E-04	-2.03E-04	-2.18E-04	-2.44E-04	-2.22E-04	-2.04E-04	
99	-1.88E-04	-1.90E-04	-1.98E-04	-1.86E-04	-2.00E-04	-2.00E-04	-1.98E-04	-2.00E-04	
100	-1.86E-04	-1.84E-04	-1.86E-04	-1.89E-04	-1.94E-04	-1.90E-04	-1.92E-04	-1.93E-04	
117	-1.86E-04	-1.86E-04	-1.95E-04	-1.88E-04	-1.83E-04	-1.99E-04	-1.94E-04	-2.02E-04	
118	-1.82E-04	-1.80E-04	-1.80E-04	-1.81E-04	-1.77E-04	-1.77E-04	-1.76E-04	-1.75E-04	
119	-1.92E-04	-1.82E-04	-1.74E-04	-1.84E-04	-1.79E-04	-1.83E-04	-1.80E-04	-1.93E-04	
Biased Statistics									
Average Biased	-1.75E-04	-1.87E-04	-1.92E-04	-1.95E-04	-2.01E-04	-2.12E-04	-2.12E-04	-2.13E-04	
Std Dev Biased	3.91E-06	4.62E-06	4.44E-06	8.26E-06	1.42E-05	2.85E-05	2.21E-05	1.24E-05	
Ps90%/90% (+KTL) Biased	-1.65E-04	-1.74E-04	-1.80E-04	-1.73E-04	-1.62E-04	-1.34E-04	-1.52E-04	-1.79E-04	
Ps90%/90% (-KTL) Biased	-1.86E-04	-1.99E-04	-2.04E-04	-2.18E-04	-2.39E-04	-2.90E-04	-2.73E-04	-2.47E-04	
Un-Biased Statistics									
Average Un-Biased	-1.81E-04	-1.85E-04	-1.92E-04	-1.91E-04	-1.95E-04	-2.06E-04	-1.99E-04	-1.97E-04	
Std Dev Un-Biased	7.81E-06	5.37E-06	4.76E-06	6.91E-06	1.54E-05	2.18E-05	1.37E-05	8.17E-06	
Ps90%/90% (+KTL) Un-Biased	-1.60E-04	-1.71E-04	-1.79E-04	-1.72E-04	-1.52E-04	-1.46E-04	-1.61E-04	-1.74E-04	
Ps90%/90% (-KTL) Un-Biased	-2.02E-04	-2.00E-04	-2.05E-04	-2.10E-04	-2.37E-04	-2.65E-04	-2.36E-04	-2.19E-04	
Specification MIN	-1.00E-03		-1.25E-03	-1.30E-03		-1.35E-03	-1.35E-03	-1.35E-03	
Status	PASS		PASS	PASS		PASS	PASS	PASS	
Specification MAX	1.00E-03		1.25E-03	1.30E-03		1.35E-03	1.35E-03	1.35E-03	
Status	PASS		PASS	PASS		PASS	PASS	PASS	

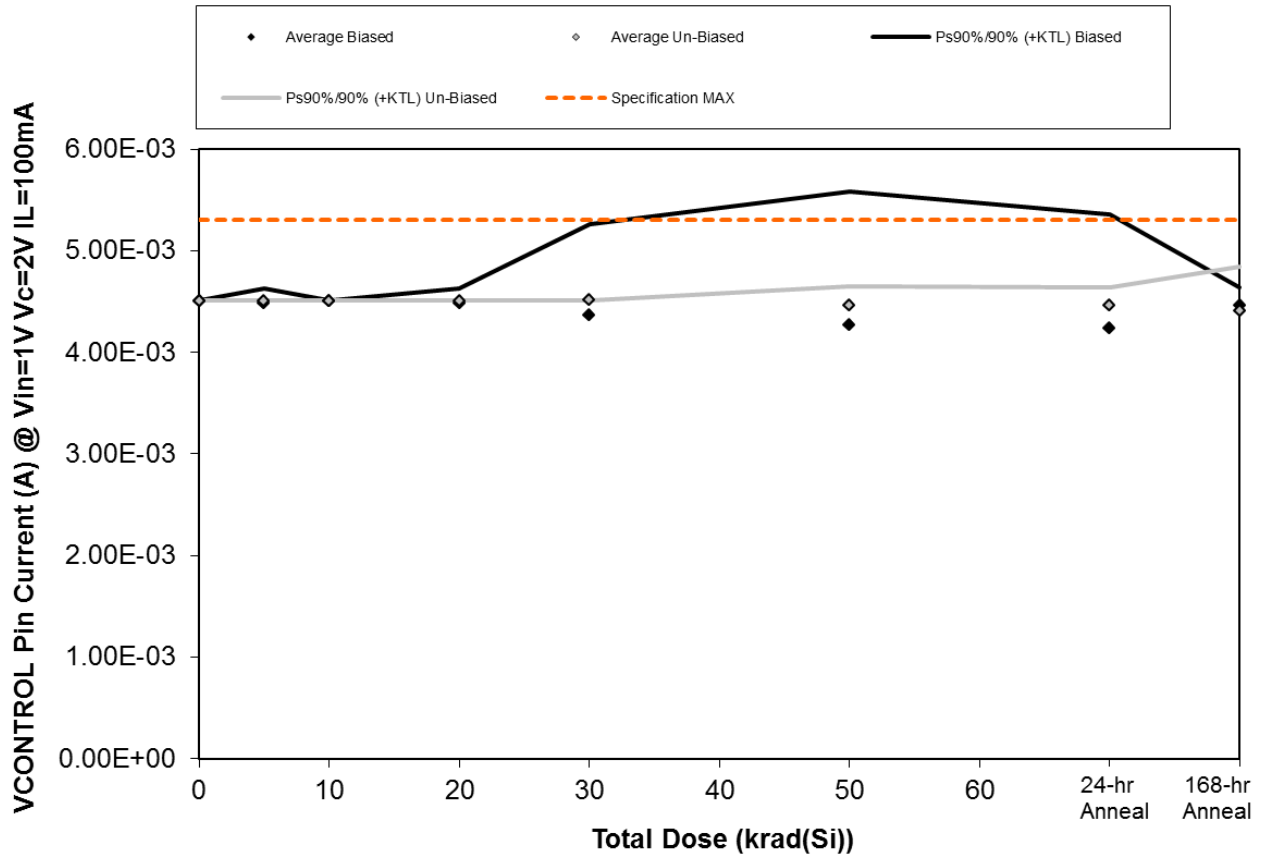


Figure 5.7. Plot of VCONTROL Pin Current (A) @ Vin=1V Vc=2V IL=100mA versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.7. Raw data for VCONTROL Pin Current (A) @ Vin=1V Vc=2V IL=100mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

VCONTROL Pin Current (A) @ Vin=1V Vc=2V IL=100mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device		0	5	10	20	30	50		
92	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03
93	4.51E-03	4.51E-03	4.51E-03	4.39E-03	4.51E-03	4.39E-03	4.51E-03	4.51E-03	4.51E-03
94	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.26E-03	4.39E-03
95	4.51E-03	4.39E-03	4.51E-03	4.51E-03	4.51E-03	3.78E-03	3.41E-03	3.53E-03	4.51E-03
96	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.39E-03	4.39E-03
97	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03
98	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.39E-03	4.14E-03
99	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.39E-03	4.39E-03	4.51E-03
100	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.39E-03	4.51E-03	4.51E-03
117	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.39E-03
118	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03
119	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03
Biased Statistics									
Average Biased	4.51E-03	4.48E-03	4.51E-03	4.48E-03	4.37E-03	4.27E-03	4.24E-03	4.46E-03	
Std Dev Biased	0.00E+00	5.50E-05	0.00E+00	5.46E-05	3.28E-04	4.81E-04	4.09E-04	6.68E-05	
Ps90%/90% (+KTL) Biased	4.51E-03	4.63E-03	4.51E-03	4.63E-03	5.27E-03	5.59E-03	5.36E-03	4.64E-03	
Ps90%/90% (-KTL) Biased	4.51E-03	4.33E-03	4.51E-03	4.33E-03	3.47E-03	2.95E-03	3.12E-03	4.28E-03	
Un-Biased Statistics									
Average Un-Biased	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.46E-03	4.46E-03	4.41E-03	
Std Dev Un-Biased	0.00E+00	0.00E+00	0.00E+00	0.00E+00	0.00E+00	6.74E-05	6.68E-05	1.59E-04	
Ps90%/90% (+KTL) Un-Biased	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.65E-03	4.64E-03	4.85E-03	
Ps90%/90% (-KTL) Un-Biased	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.51E-03	4.28E-03	4.28E-03	3.98E-03	
Specification MAX	5.30E-03		5.30E-03	5.30E-03		5.30E-03	5.30E-03	5.30E-03	
Status	PASS		PASS	PASS		PASS	PASS	PASS	

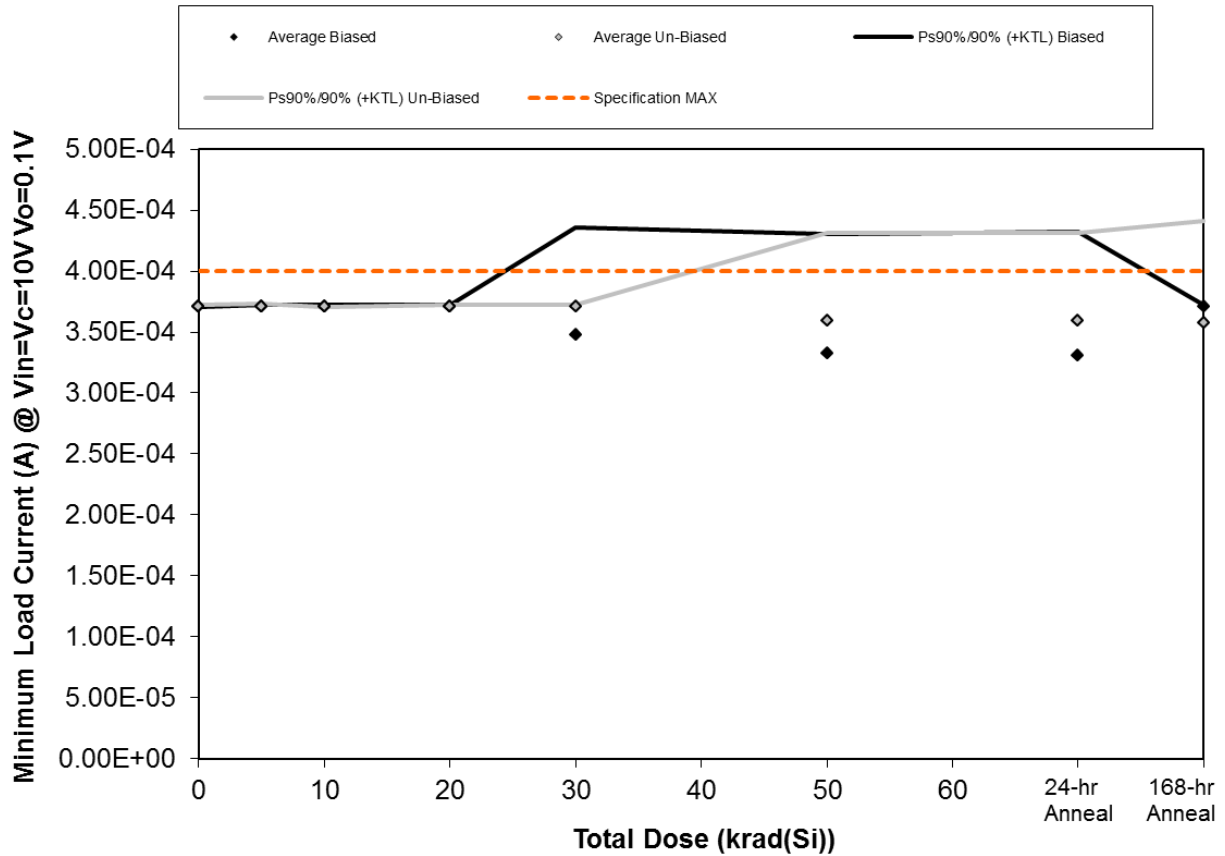


Figure 5.8. Plot of Minimum Load Current (A) @ $V_{in}=V_c=10V$ $V_o=0.1V$ versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.8. Raw data for Minimum Load Current (A) @ Vin=Vc=10V Vo=0.1V versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

Minimum Load Current (A) @ Vin=Vc=10V Vo=0.1V		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device	0	5	10	20	30	50			
92	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.12E-04	3.12E-04	3.04E-04	3.71E-04	
93	3.71E-04	3.72E-04	3.72E-04	3.72E-04	3.13E-04	2.96E-04	2.96E-04	3.72E-04	
94	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	
95	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.13E-04	3.12E-04	3.71E-04	
96	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	
97	3.72E-04	3.72E-04	3.71E-04	3.72E-04	3.72E-04	3.72E-04	3.72E-04	3.72E-04	
98	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.72E-04	3.72E-04	3.72E-04	
99	3.71E-04	3.72E-04	3.71E-04	3.71E-04	3.71E-04	3.13E-04	3.13E-04	3.04E-04	
100	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	
117	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	
118	3.71E-04	3.72E-04	3.71E-04	3.71E-04	3.71E-04	3.72E-04	3.71E-04	3.72E-04	
119	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	
Biased Statistics									
Average Biased	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.48E-04	3.33E-04	3.31E-04	3.71E-04	
Std Dev Biased	0.00E+00	4.47E-07	4.47E-07	4.47E-07	3.20E-05	3.57E-05	3.71E-05	4.47E-07	
Ps90%/90% (+KTL) Biased	3.71E-04	3.72E-04	3.72E-04	3.72E-04	4.35E-04	4.30E-04	4.33E-04	3.72E-04	
Ps90%/90% (-KTL) Biased	3.71E-04	3.70E-04	3.70E-04	3.70E-04	2.60E-04	2.35E-04	2.29E-04	3.70E-04	
Un-Biased Statistics									
Average Un-Biased	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.71E-04	3.60E-04	3.60E-04	3.58E-04	
Std Dev Un-Biased	4.47E-07	5.48E-07	0.00E+00	4.47E-07	4.47E-07	2.62E-05	2.62E-05	3.02E-05	
Ps90%/90% (+KTL) Un-Biased	3.72E-04	3.73E-04	3.71E-04	3.72E-04	3.72E-04	4.32E-04	4.32E-04	4.41E-04	
Ps90%/90% (-KTL) Un-Biased	3.70E-04	3.70E-04	3.71E-04	3.70E-04	3.70E-04	2.88E-04	2.88E-04	2.75E-04	
Specification MAX	4.00E-04		4.00E-04	4.00E-04		4.00E-04	4.00E-04	4.00E-04	
Status	PASS		PASS	PASS		PASS	PASS	PASS	

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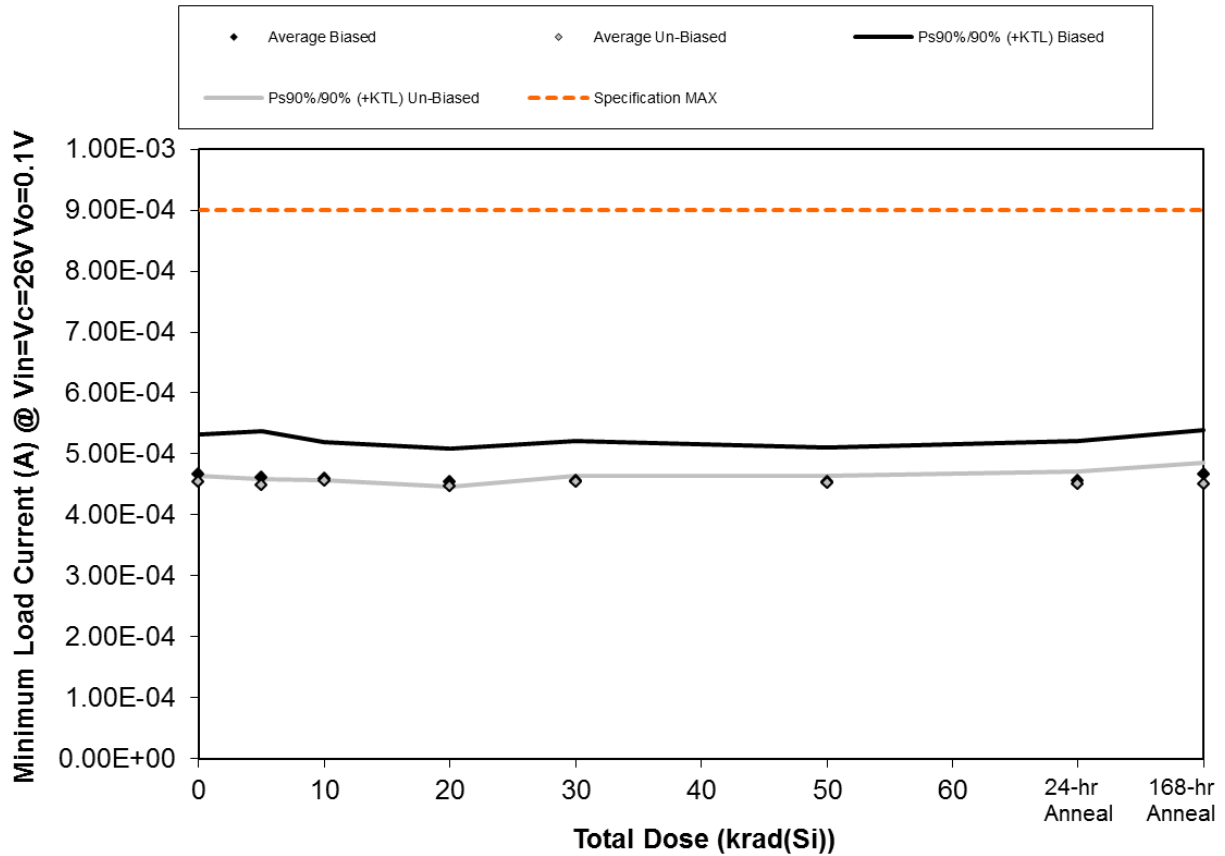


Figure 5.9. Plot of Minimum Load Current (A) @ $V_{in}=V_c=26V$ $V_o=0.1V$ versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.9. Raw data for Minimum Load Current (A) @ Vin=Vc=26V Vo=0.1V versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

Minimum Load Current (A) @ Vin=Vc=26V Vo=0.1V		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device		0	5	10	20	30	50		
92	4.47E-04	4.39E-04	4.38E-04	4.38E-04	4.38E-04	4.39E-04	4.38E-04	4.39E-04	4.39E-04
93	4.72E-04	4.72E-04	4.56E-04	4.47E-04	4.47E-04	4.39E-04	4.39E-04	4.73E-04	4.73E-04
94	4.55E-04	4.47E-04	4.55E-04	4.47E-04	4.55E-04	4.55E-04	4.55E-04	4.47E-04	4.47E-04
95	5.06E-04	5.06E-04	4.97E-04	4.89E-04	4.97E-04	4.89E-04	4.97E-04	5.06E-04	5.06E-04
96	4.55E-04	4.47E-04	4.55E-04	4.47E-04	4.47E-04	4.47E-04	4.47E-04	4.72E-04	4.72E-04
97	4.47E-04	4.48E-04	4.56E-04	4.47E-04	4.56E-04	4.56E-04	4.56E-04	4.48E-04	4.48E-04
98	4.55E-04	4.55E-04	4.55E-04	4.47E-04	4.55E-04	4.47E-04	4.47E-04	4.72E-04	4.72E-04
99	4.55E-04	4.47E-04	4.56E-04	4.47E-04	4.47E-04	4.47E-04	4.39E-04	4.39E-04	4.39E-04
100	4.55E-04	4.47E-04	4.55E-04	4.47E-04	4.55E-04	4.55E-04	4.55E-04	4.47E-04	4.47E-04
117	4.55E-04	4.47E-04	4.55E-04	4.47E-04	4.55E-04	4.55E-04	4.55E-04	4.47E-04	4.47E-04
118	4.72E-04	4.72E-04	4.72E-04	4.72E-04	4.72E-04	4.72E-04	4.72E-04	4.72E-04	4.72E-04
119	4.72E-04	4.55E-04	4.55E-04	4.55E-04	4.55E-04	4.55E-04	4.55E-04	4.72E-04	4.72E-04
Biased Statistics									
Average Biased	4.67E-04	4.62E-04	4.60E-04	4.54E-04	4.57E-04	4.54E-04	4.55E-04	4.67E-04	4.67E-04
Std Dev Biased	2.36E-05	2.75E-05	2.19E-05	2.02E-05	2.33E-05	2.08E-05	2.44E-05	2.63E-05	2.63E-05
Ps90%/90% (+KTL) Biased	5.32E-04	5.37E-04	5.20E-04	5.09E-04	5.21E-04	5.11E-04	5.22E-04	5.39E-04	5.39E-04
Ps90%/90% (-KTL) Biased	4.02E-04	3.87E-04	4.00E-04	3.98E-04	3.93E-04	3.97E-04	3.88E-04	3.95E-04	3.95E-04
Un-Biased Statistics									
Average Un-Biased	4.53E-04	4.49E-04	4.55E-04	4.47E-04	4.54E-04	4.52E-04	4.50E-04	4.51E-04	4.51E-04
Std Dev Un-Biased	3.58E-06	3.49E-06	5.48E-07	0.00E+00	3.71E-06	4.58E-06	7.33E-06	1.25E-05	1.25E-05
Ps90%/90% (+KTL) Un-Biased	4.63E-04	4.58E-04	4.57E-04	4.47E-04	4.64E-04	4.65E-04	4.71E-04	4.85E-04	4.85E-04
Ps90%/90% (-KTL) Un-Biased	4.44E-04	4.39E-04	4.54E-04	4.47E-04	4.43E-04	4.39E-04	4.30E-04	4.16E-04	4.16E-04
Specification MAX	9.00E-04		9.00E-04	9.00E-04		9.00E-04	9.00E-04	9.00E-04	9.00E-04
Status	PASS		PASS	PASS		PASS	PASS	PASS	PASS

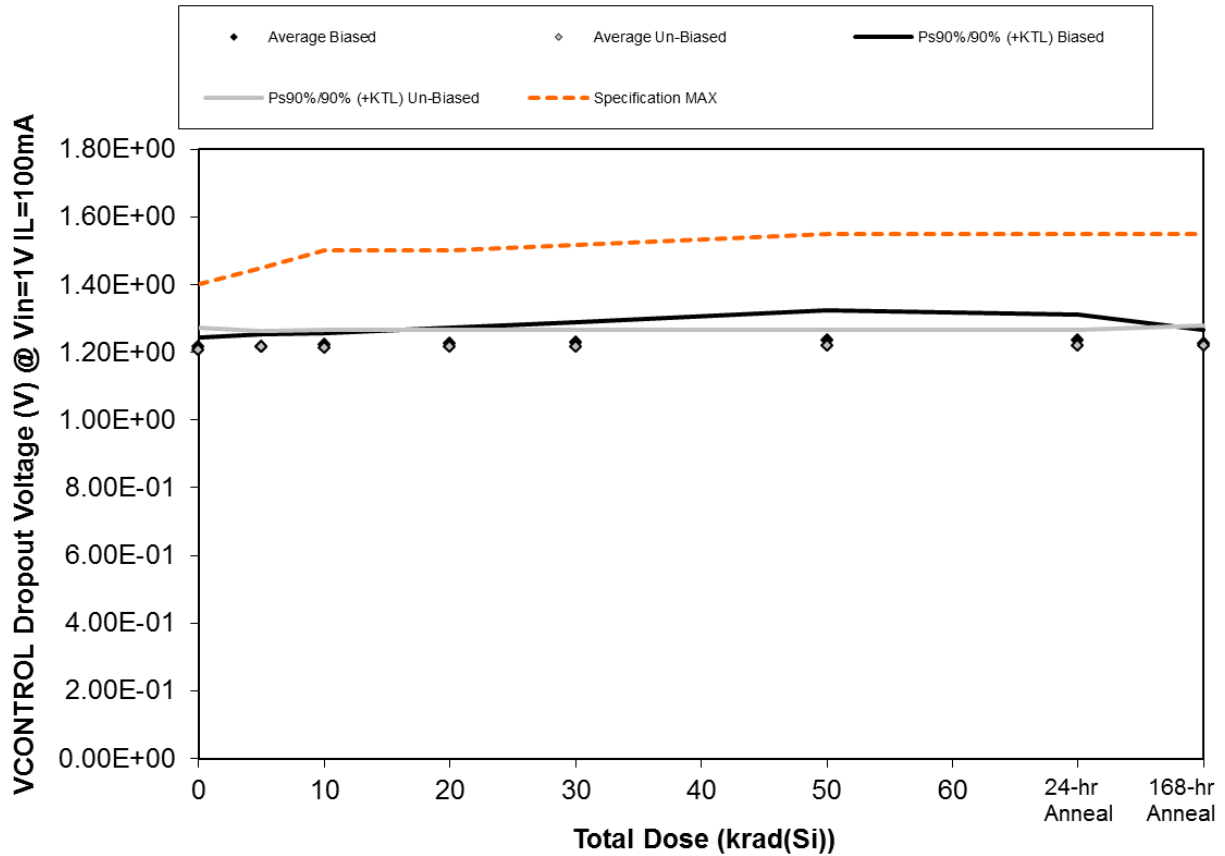


Figure 5.10. Plot of VCONTROL Dropout Voltage (V) @ $V_{in}=1V$ $I_L=100mA$ versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.10. Raw data for VCONTROL Dropout Voltage (V) @ Vin=1V IL=100mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

VCONTROL Dropout Voltage (V) @ Vin=1V IL=100mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device		0	5	10	20	30	50		
92	1.21E+00	1.21E+00	1.22E+00	1.22E+00	1.22E+00	1.22E+00	1.22E+00	1.22E+00	1.23E+00
93	1.20E+00	1.21E+00	1.21E+00	1.22E+00	1.22E+00	1.22E+00	1.23E+00	1.23E+00	1.22E+00
94	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.22E+00	1.22E+00	1.22E+00	1.22E+00	1.21E+00
95	1.23E+00	1.24E+00	1.24E+00	1.26E+00	1.27E+00	1.29E+00	1.29E+00	1.29E+00	1.25E+00
96	1.22E+00	1.22E+00	1.23E+00	1.22E+00	1.23E+00	1.23E+00	1.23E+00	1.23E+00	1.21E+00
97	1.23E+00	1.23E+00	1.22E+00	1.23E+00	1.23E+00	1.23E+00	1.23E+00	1.23E+00	1.23E+00
98	1.24E+00	1.24E+00	1.24E+00	1.24E+00	1.24E+00	1.24E+00	1.24E+00	1.25E+00	1.26E+00
99	1.20E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00
100	1.19E+00	1.20E+00	1.19E+00	1.20E+00	1.19E+00	1.20E+00	1.20E+00	1.20E+00	1.20E+00
117	1.20E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.21E+00	1.22E+00
118	1.20E+00	1.21E+00	1.21E+00	1.20E+00	1.20E+00	1.20E+00	1.20E+00	1.20E+00	1.20E+00
119	1.20E+00	1.21E+00	1.20E+00	1.20E+00	1.21E+00	1.20E+00	1.20E+00	1.21E+00	1.20E+00
Biased Statistics									
Average Biased	1.22E+00	1.22E+00	1.22E+00	1.23E+00	1.23E+00	1.24E+00	1.24E+00	1.24E+00	1.23E+00
Std Dev Biased	1.07E-02	1.35E-02	1.33E-02	1.70E-02	2.19E-02	3.19E-02	2.78E-02	1.50E-02	
Ps90%/90% (+KTL) Biased	1.25E+00	1.25E+00	1.26E+00	1.27E+00	1.29E+00	1.32E+00	1.31E+00	1.27E+00	
Ps90%/90% (-KTL) Biased	1.19E+00	1.18E+00	1.19E+00	1.18E+00	1.17E+00	1.15E+00	1.16E+00	1.18E+00	
Un-Biased Statistics									
Average Un-Biased	1.21E+00	1.22E+00	1.21E+00	1.22E+00	1.22E+00	1.22E+00	1.22E+00	1.22E+00	1.22E+00
Std Dev Un-Biased	2.37E-02	1.74E-02	1.88E-02	1.85E-02	1.91E-02	1.72E-02	1.71E-02	2.12E-02	
Ps90%/90% (+KTL) Un-Biased	1.27E+00	1.26E+00	1.27E+00	1.27E+00	1.27E+00	1.27E+00	1.27E+00	1.28E+00	
Ps90%/90% (-KTL) Un-Biased	1.14E+00	1.17E+00	1.16E+00	1.16E+00	1.16E+00	1.17E+00	1.17E+00	1.16E+00	
Specification MAX	1.40E+00		1.50E+00	1.50E+00		1.55E+00	1.55E+00	1.55E+00	
Status	PASS		PASS	PASS		PASS	PASS	PASS	

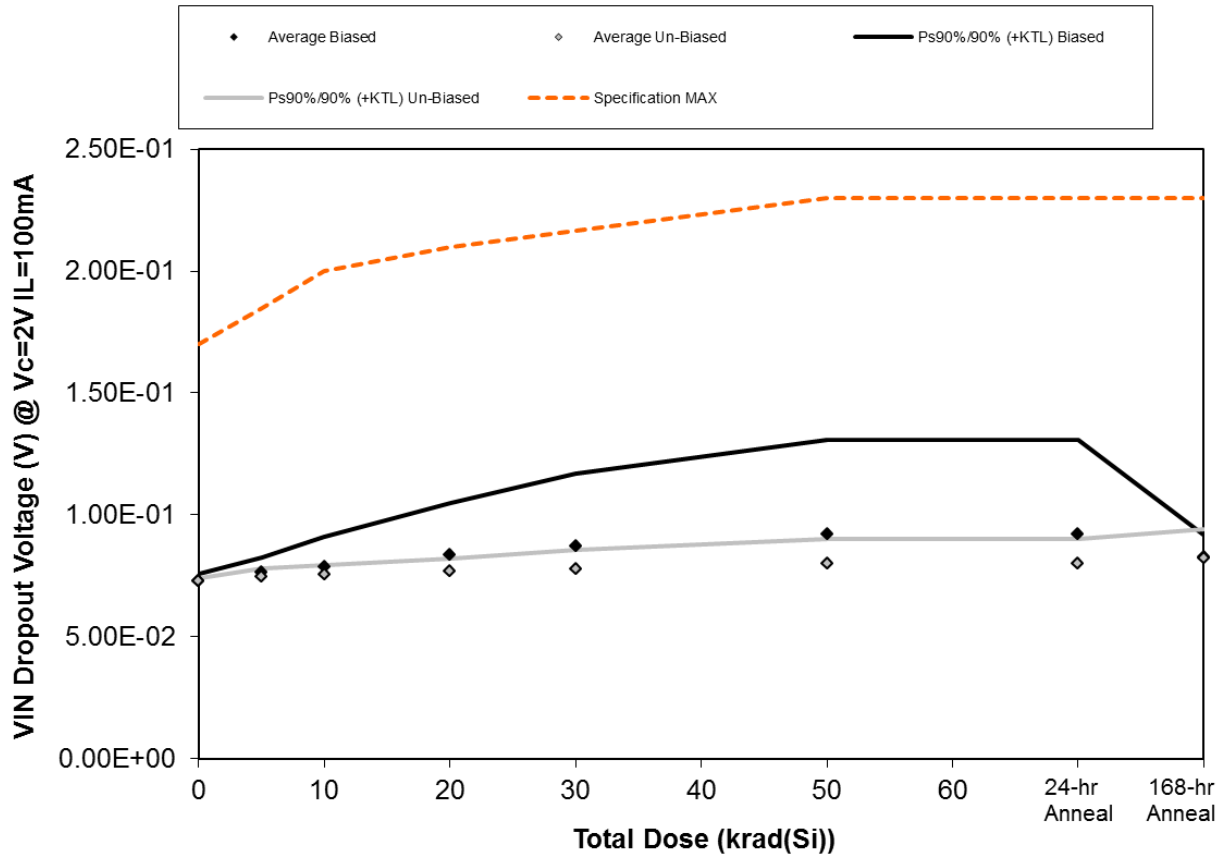


Figure 5.11. Plot of VIN Dropout Voltage (V) @ Vc=2V IL=100mA versus total dose. The solid diamonds are the average of the measured data points for the samples irradiated under electrical bias while the shaded diamonds are the average of the measured data points for the samples irradiated with all pins tied to ground. The black lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated under electrical bias while the gray lines (solid and/or dashed) are the upper and/or lower confidence limits, as determined by KTL statistics, on the samples irradiated in the unbiased condition. The red dotted line(s) are the pre- and/or post-irradiation minimum and/or maximum specification value as defined in the datasheet and/or test plan.



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Table 5.11. Raw data for VIN Dropout Voltage (V) @ Vc=2V IL=100mA versus total dose, including the statistical analysis, specification and the status of the testing (pass/fail).

VIN Dropout Voltage (V) @ Vc=2V IL=100mA		Total Dose (krad(Si))						24-hr Anneal	168-hr Anneal
Device	0	5	10	20	30	50			
92	7.40E-02	7.60E-02	7.70E-02	8.00E-02	8.20E-02	8.50E-02	8.50E-02	8.20E-02	
93	7.20E-02	7.70E-02	8.00E-02	8.60E-02	9.20E-02	1.00E-01	1.00E-01	8.30E-02	
94	7.20E-02	7.40E-02	7.50E-02	7.70E-02	7.70E-02	7.90E-02	7.90E-02	7.90E-02	
95	7.30E-02	8.00E-02	8.60E-02	9.60E-02	1.04E-01	1.13E-01	1.13E-01	8.80E-02	
96	7.40E-02	7.60E-02	7.60E-02	7.90E-02	8.10E-02	8.40E-02	8.30E-02	8.20E-02	
97	7.20E-02	7.40E-02	7.40E-02	7.60E-02	7.60E-02	7.70E-02	7.70E-02	7.80E-02	
98	7.30E-02	7.60E-02	7.70E-02	7.90E-02	8.10E-02	8.50E-02	8.40E-02	8.70E-02	
99	7.30E-02	7.60E-02	7.70E-02	7.90E-02	8.10E-02	8.30E-02	8.40E-02	8.60E-02	
100	7.30E-02	7.40E-02	7.40E-02	7.50E-02	7.60E-02	7.70E-02	7.70E-02	7.80E-02	
117	7.30E-02	7.40E-02	7.50E-02	7.60E-02	7.60E-02	7.80E-02	7.80E-02	8.20E-02	
118	7.30E-02	7.30E-02	7.30E-02	7.30E-02	7.30E-02	7.30E-02	7.30E-02	7.30E-02	
119	7.20E-02	7.30E-02	7.20E-02	7.20E-02	7.20E-02	7.20E-02	7.20E-02	7.20E-02	
Biased Statistics									
Average Biased	7.30E-02	7.66E-02	7.88E-02	8.36E-02	8.72E-02	9.22E-02	9.20E-02	8.28E-02	
Std Dev Biased	1.00E-03	2.19E-03	4.44E-03	7.70E-03	1.09E-02	1.40E-02	1.42E-02	3.27E-03	
Ps90%/90% (+KTL) Biased	7.57E-02	8.26E-02	9.10E-02	1.05E-01	1.17E-01	1.31E-01	1.31E-01	9.18E-02	
Ps90%/90% (-KTL) Biased	7.03E-02	7.06E-02	6.66E-02	6.25E-02	5.73E-02	5.37E-02	5.31E-02	7.38E-02	
Un-Biased Statistics									
Average Un-Biased	7.28E-02	7.48E-02	7.54E-02	7.70E-02	7.80E-02	8.00E-02	8.00E-02	8.22E-02	
Std Dev Un-Biased	4.47E-04	1.10E-03	1.52E-03	1.87E-03	2.74E-03	3.74E-03	3.67E-03	4.27E-03	
Ps90%/90% (+KTL) Un-Biased	7.40E-02	7.78E-02	7.96E-02	8.21E-02	8.55E-02	9.03E-02	9.01E-02	9.39E-02	
Ps90%/90% (-KTL) Un-Biased	7.16E-02	7.18E-02	7.12E-02	7.19E-02	7.05E-02	6.97E-02	6.99E-02	7.05E-02	
Specification MAX	1.70E-01		2.00E-01	2.10E-01		2.30E-01	2.30E-01	2.30E-01	
Status	PASS		PASS	PASS		PASS	PASS	PASS	



6.0. Summary / Conclusions

The low dose rate testing described in this final report was performed using the facilities at Aeroflex RAD's Longmire Laboratories in Colorado Springs, CO. The low dose rate source is a GB-150 irradiator modified to provide a panoramic exposure. The Co-60 rods are held in the base of the irradiator heavily shielded by lead. During the irradiation exposures the rod is raised by an electronic timer/controller and the exposure is performed in air. The dose rate for this irradiator in this configuration ranges from approximately 1mrad(Si)/s to a maximum of approximately 50rad(Si)/s, determined by the distance from the source.

The parametric data was obtained as "read and record" and all the raw data plus an attributes summary are contained in this report as well as in a separate Excel file. The attributes data contains the average, standard deviation and the average with the KTL values applied. The KTL value used in this work is 2.742 per MIL-HDBK-814 using one sided tolerance limits of 90/90 and a 5-piece sample size. The 90/90 KTL values were selected to match the statistical levels specified in the MIL-PRF-38535 sampling plan for the qualification of a radiation hardness assured (RHA) component. Note that the following criteria must be met for a device to pass the low dose rate test: following the radiation exposure each of the 5 pieces irradiated under electrical bias shall pass the specification value. The units irradiated without electrical bias and the KTL statistics are included in this report for reference only. If any of the 5 pieces irradiated under electrical bias exceed the device post radiation data sheet specification limits, then the lot could be logged as a failure.

Based on this criterion the RH3080MK Adjustable Low Dropout Regulator (from the lot traceability information provided on the first page of this test report) PASSED the enhanced low dose rate sensitivity test to the maximum tested dose level of 50krad(Si) with one exception, ISET Line Regulation was out of specification. Note that the variation in ISET Line Regulation of the irradiated units is due to the instruments measurement resolution/precision (see Table C2). Further, the data in this report can be analyzed along with the high dose rate report titled "Total Ionizing Dose (TID) Radiation Testing of the RH3080MK Adjustable Low Dropout Regulator for Linear Technology" to demonstrate that these parts do not exhibit ELDRS as defined in MIL-STD-883H, TM 1019.8.



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Appendix A: Photograph of a Sample Unit-Under-Test to Show Part Traceability



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Appendix B: Radiation Bias Connections

TID Radiation Biased Conditions: Extracted from Linear Technology RH3080MK SPEC NO. 05-08-5246 REV. 0.

Pin	Function	Connection / Bias
1	NC	NC
2	SET	To GND via 49.9k Ω
3	V CONTROL	To Pin 4
4	IN	+3V To GND via 1 μ F To Pin 3
5	OUT	To GND via 10 μ F To GND via 499 Ω

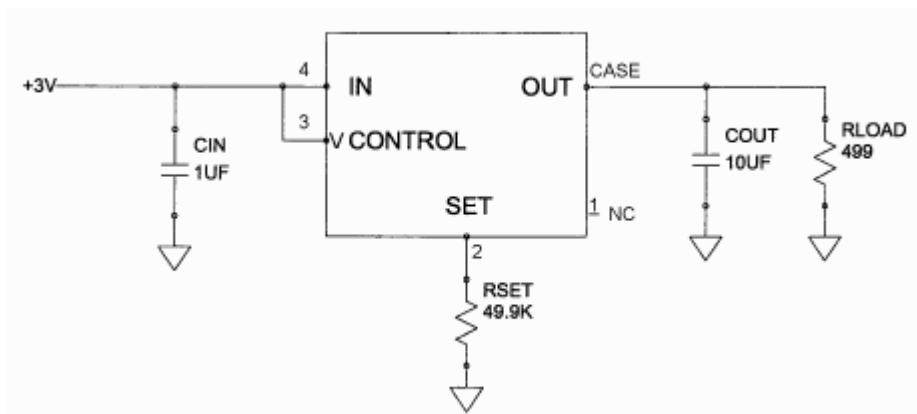


Figure B.1. Irradiation bias circuit. This figure was extracted from Linear Technology RH3080MK SPEC NO. 05-08-5246 REV. 0.



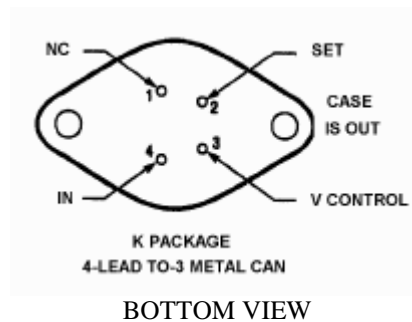
TID Radiation Unbiased Conditions:

Pin	Function	Connection / Bias
1	NC	GND
2	SET	GND
3	V CONTROL	GND
4	IN	GND
CASE	OUT	GND

Absolute Maximum Rating:

Parameter	Max Rating
V CONTROL Pin Voltage	40V, -0.3V
IN Pin Voltage	40V, -0.3V
SET Pin Current	$\pm 10\text{mA}$
SET Pin Voltage (Relative to OUT)	$\pm 0.3\text{V}$

Figure B.2. K package drawing (for reference only). This figure was extracted from the Linear Technology RH3080MK datasheet 2014.





Appendix C: Electrical Test Parameters and Conditions

The expected ranges of values as well as the measurement conditions are taken from Linear Technology RH3080MK SPEC NO. 05-08-5246 REV. 0. All electrical tests for this device are performed on one of Aeroflex RAD's LTS2020 Test Systems. The LTS2020 Test System is a programmable parametric tester that provides parameter measurements for a variety of digital, analog and mixed signal products including voltage regulators, voltage comparators, D to A and A to D converters. The LTS2020 Test System achieves accuracy and sensitivity through the use of software self-calibration and an internal relay matrix with separate family boards and custom personality adapter boards. The tester uses this relay matrix to connect the required test circuits, select the appropriate voltage / current sources and establish the needed measurement loops for all the tests performed. The measured parameters and test conditions are shown in Table C.1.

A listing of the measurement precision/resolution for each parameter is shown in Table C.2. The precision/resolution values were obtained from test data or from the DAC resolution of the LTS-2020 for the particular test shown, whichever is greater. To generate the precision/resolution shown in Table C.2, one of the units-under-test was tested repetitively (a total of 10-times with re-insertion between tests) to obtain the average test value and standard deviation. Using this test data MIL-HDBK-814 90/90 KTL statistics were applied to the measured standard deviation to generate the final measurement range. This value encompasses the precision/resolution of all aspects of the test system, including the LTS2020 mainframe, family board, socket assembly and DUT board as well as insertion error. In some cases, the measurement resolution is limited by the internal DACs, which results in a measured standard deviation of zero. In these instances the precision/resolution will be reported back as the LSB of the DAC.

Note that the testing and statistics used in this document are based on an "analysis of variables" technique, which relies on small sample sizes to qualify much larger lot sizes (see MIL-HDBK-814, p. 91 for a discussion of statistical treatments). Not all measured parameters are well suited to this approach due to inherent large variations. If necessary, larger samples sizes could be used to qualify these parameters using an "attributes" approach.



Table C.1. Measured parameters and test conditions for the RH3080MK Adjustable Low Dropout Regulator.

Parameter	Symbol	Test Conditions
SET Pin Current (A)	ISET	Vin=1V Vc=2V IL=1mA
Output Offset Voltage (V)	VOS	Vin=1V Vc=2V IL=1mA
ISET Line Regulation (nA/V)	ISET LN REG	Vc=2 to 26V IL=1mA
VOS Line Regulation (mV/V)	VOS LN REG	Vc=2 to 26V IL=1mA
ISET Load Regulation (A)	ISET LOAD REG	IL=1mA to 100mA
VOS Load Regulation (V)	VOS LOAD REG	IL=1mA to 100mA
VCONTROL Pin Current (A)	ICONTROL	Vin=1V Vc=2V IL=100mA
Minimum Load Current (A)	IMIN	VP=VC=10V VO=0.1V
		VP=VC=26V VO=0.1V
VCONTROL Dropout Voltage (V)	VC DROPOUT	Vin=1V IL=100mA
VIN Dropout Voltage (V)	VP DROPOUT	Vc=2V IL=100mA

Table C.2. Measured parameters, pre-irradiation specifications and measurement precision for the RH3080MK Adjustable Low Dropout Regulator.

Parameter	Pre-Irradiation Specification		Measurement Precision/Resolution
	MIN	MAX	
ISET	9.90E-06	1.01E-05	±6.69E-09
VOS	-5.00E-03	5.00E-03	±5.94E-06
ISET LN REG	-4.50E-01	4.50E-01	±3.25E-01
VOS LN REG	-5.00E-02	5.00E-02	±1.00E-03
ISET LOAD REG	-1.50E-08	1.50E-08	±7.75E-09
VOS LOAD REG	-1.00E-03	1.00E-03	±3.29E-06
ICONTROL		5.30E-03	±0.00E+00
IMIN (VP=VC=10V)		4.00E-04	±8.00E-06
IMIN (VP=VC=26V)		9.00E-04	±8.00E-06
VC DROPOUT		1.40E+00	±4.51E-03
VP DROPOUT		1.70E-01	±8.71E-04



Appendix D: List of Figures Used in the Results Section (Section 5)

- 5.1. SET Pin Current (A) @ $V_{in}=1V$ $V_c=2V$ $I_L=1mA$
- 5.2. Output Offset Voltage (V) @ $V_{in}=1V$ $V_c=2V$ $I_L=1mA$
- 5.3. ISET Line Regulation (nA/V) @ $V_c=2$ to $26V$ $I_L=1mA$
- 5.4. VOS Line Regulation (mV/V) @ $V_c=2$ to $26V$ $I_L=1mA$
- 5.5. ISET Load Regulation (A) @ $I_L=1mA$ to $100mA$
- 5.6. VOS Load Regulation (V) @ $I_L=1mA$ to $100mA$
- 5.7. VCONTROL Pin Current (A) @ $V_{in}=1V$ $V_c=2V$ $I_L=100mA$
- 5.8. Minimum Load Current (A) @ $V_{in}=V_c=10V$ $V_o=0.1V$
- 5.9. Minimum Load Current (A) @ $V_{in}=V_c=26V$ $V_o=0.1V$
- 5.10. VCONTROL Dropout Voltage (V) @ $V_{in}=1V$ $I_L=100mA$
- 5.11. VIN Dropout Voltage (V) @ $V_c=2V$ $I_L=100mA$